Piezoelectric Ring Chip, 150 V, 3.9 µm Travel

PA44M3K



Description

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The PA44M3K piezoelectric ring chip has a 15.0 mm outer diameter and a 9.0 mm inner diameter. It consists of a series of stacked piezoelectric ceramic layers, each possessing screen-printed electrodes. The printed layers are isostatically pressed to form the chip. The electrodes are electrically in parallel and the PA44M3K provides a maximum displacement of 3.9 μ m ± 15%. A silver dot is located next to the electrode that should receive positive bias; the other electrode should be grounded. The electrodes are bare.

Specifications

| PA44M3K ^a | |
|--|--|
| Drive Voltage Range | 0 - 150 V |
| Displacement (Free Stroke) at 150 V ^b | 3.9 μm ± 15% |
| Hysteresis | <15% (See Graph on Next Page) |
| Load for Maximum Displacement ^c | 1810 N (406 lbs) |
| Blocking Force at 150V | 4520 N (1015 lbs) |
| Resonant Frequency | 260 kHz (No Load) |
| Impedance at Resonant Frequency | 100 mΩ |
| Anti-Resonant Frequency | 485 kHz |
| Dissipation Factor ^d | <2.0% |
| Capacitance ^d | 2.2 μF ± 15% |
| Operating Temperature | -25 to 130 °C |
| Curie Temperature | 230 °C |
| External Electrodes | Screen-Printed Silver |
| Dimonsions | Outer Diameter: 15.0 mm ± 0.1 mm |
| Dimensions | Inner Diameter: 9.0 mm ± 0.1 mm Length: 3.2 mm ± 5 µm |



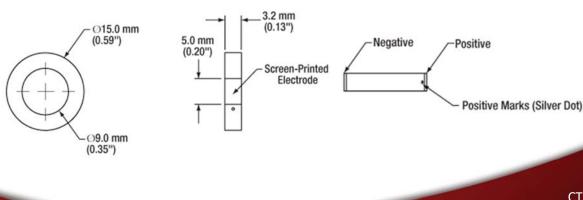
a. All specifications are quoted at 25 °C, unless otherwise stated.

b. The "free stroke" displacement corresponds to no load.

c. Displacement varies with loading. When used with this load, these chips achieve the maximum displacement, which is larger than the free stroke displacement.

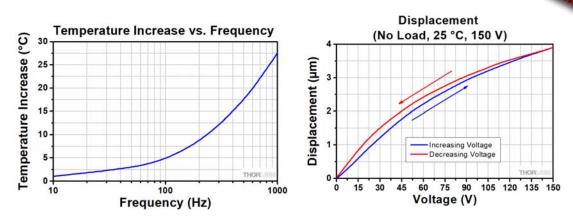
d. Specified at 1 kHz, 1 $V_{\text{RMS}}.$

Drawing



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Typical Performance Plots



The temperature increase of the chip was measured after applying a sine-wave drive voltage, with maximum and peak-to-peak amplitudes of 150 V, at the specified frequency for 10 minutes.

Operation

Electrical Considerations

- The electrode closest to the silver dot should be connected to the output port or positive pole of a driver or controller or amplifier, and the opposite electrode should be grounded. The maximum drive voltage is 150 V. Exceeding 150 V will decrease the device's lifespan and may cause mechanical failure. Reverse biasing the device may cause mechanical failure.
- When soldering wires to the electrodes, use a temperature no greater than 370 °C (700 °F) for a maximum of 2 seconds per spot. Solder to the middle of the electrode, keeping the spot as small as possible.
- Caution: After driving, the piezo is fully charged. Directly connecting the positive and negative electrodes has the risk of electricity discharging, spark, and even failure. We recommend using a resistor (>10 k Ω) between the electrodes to release the charge.

Attaching Devices to the Piezo

- Any epoxy that cures at a temperature lower than 80 °C is safe to use. We recommend Thorlabs Item #s 353NDPK or TS10. Loctite® Hysol® 9340 is also usable.
- Loads should only be attached to the central area of the largest face since the edges do not translate. Attaching a load to the smaller faces may lead to mechanical failure.

Storage Instructions

- Do not store the device at temperatures above 80 °C.
- Do not store the device in humid environments. The relative humidity (RH) should be less than 40%.
- Do not immerse the device in organic solvents.
- Do not use the device around combustible gases or liquids.

July 22, 2020 CTN015329-S01, Rev B www.thorlabs.com/contact